

## NCE0202ZA

## NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

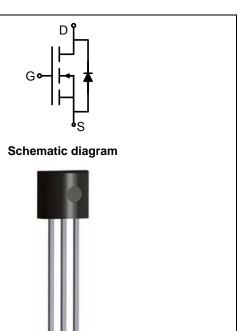
The NCE0202ZA uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

- $V_{DS}$  = 200V, $I_{D}$  =2A  $R_{DS(ON)}$  < 580mΩ @  $V_{GS}$ =10V (Typ:520mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

## **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



TO-92 view

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
0202ZA	NCE0202ZA	TO-92	-	-	-

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	200	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	2	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	8	Α
Maximum Power Dissipation	P <sub>D</sub>	3	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}\mathbb{C}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	41.7	°C/W
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## **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	200	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μΑ

Page 1 v1.0



# NCE0202ZA

Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics (Note 3)			•	•		
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	1.2	1.8	2.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =2A	-	520	580	mΩ
Forward Transconductance	<b>9</b> FS	V <sub>DS</sub> =15V,I <sub>D</sub> =2A	-	8	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -25\/\/ -0\/	-	580	-	PF
Output Capacitance	$C_{oss}$	$V_{DS}$ =25V, $V_{GS}$ =0V, F=1.0MHz	-	90	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WHZ	-	3	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =100V, R <sub>L</sub> =15Ω	-	12	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =2.5 $\Omega$	-	15	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg	\/ -100\/ L -24	-	12		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =100V, $I_{D}$ =2A, $V_{GS}$ =10V	-	2.5	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	3.8	-	nC
Drain-Source Diode Characteristics	<u>.</u>					
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =2A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	2	Α

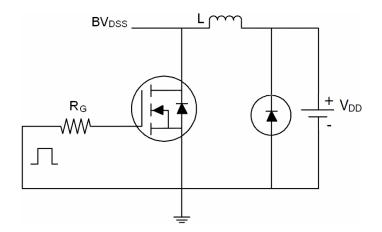
## Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature}.$
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

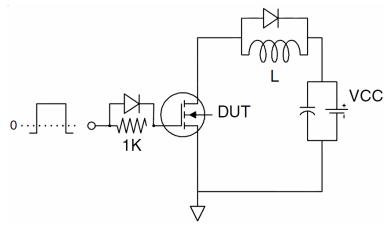


## **Test Circuit**

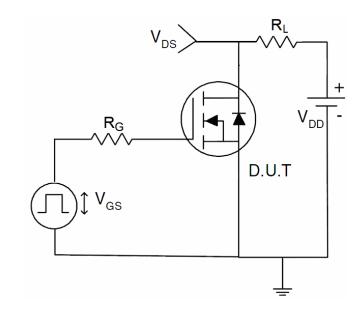
## 1) E<sub>AS</sub> test circuit



## 2) Gate charge test circuit



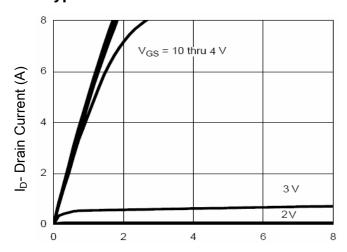
## 3) Switch Time Test Circuit



Page 3 v1.0

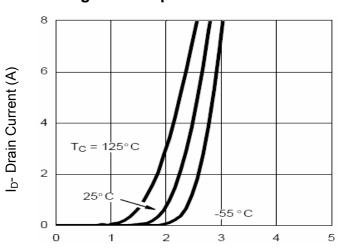


## **Typical Electrical and Thermal Characteristics (Curves)**



Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics



Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics

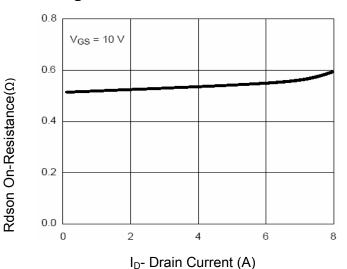


Figure 3 Rdson- Drain Current

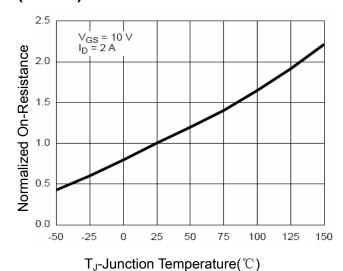
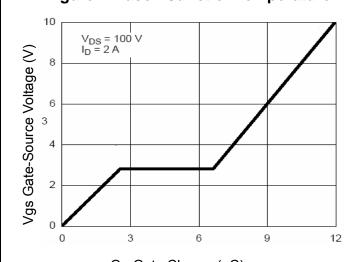


Figure 4 Rdson-JunctionTemperature



Qg Gate Charge (nC)
Figure 5 Gate Charge

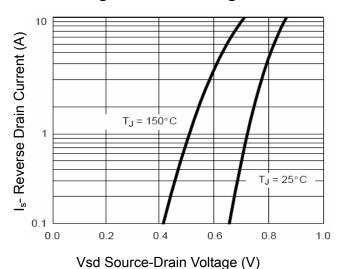
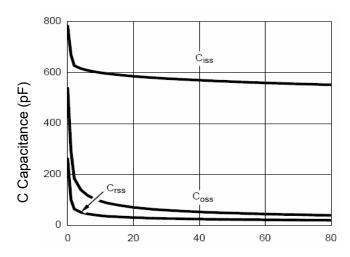


Figure 6 Source- Drain Diode Forward

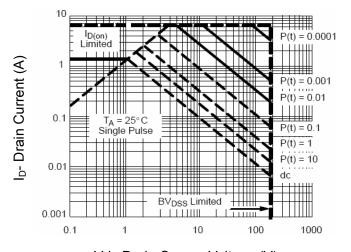
Page 4 v1.0





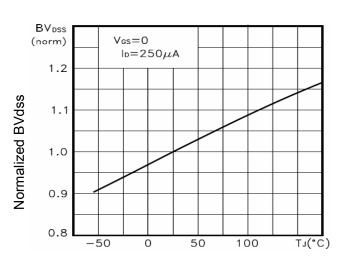
Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds



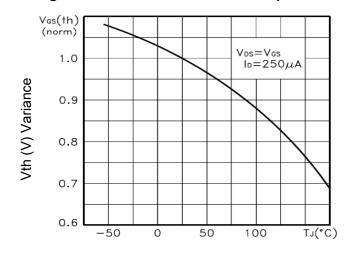
Vds Drain-Source Voltage (V)

**Figure 8 Safe Operation Area** 



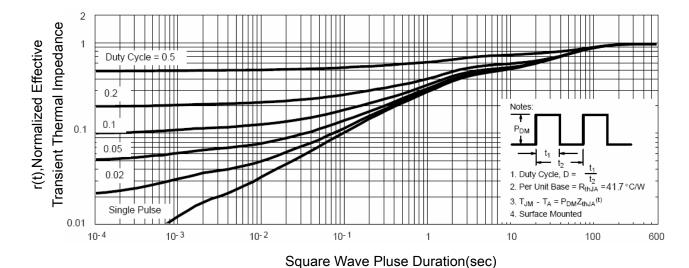
 $T_J$ -Junction Temperature( $^{\circ}$ C)

## Figure 9 BV<sub>DSS</sub> vs Junction Temperature



 $T_{J}\text{-Junction Temperature}({}^{\circ}\!\mathbb{C})$ 

Figure 10 V<sub>GS(th)</sub> vs Junction Temperature

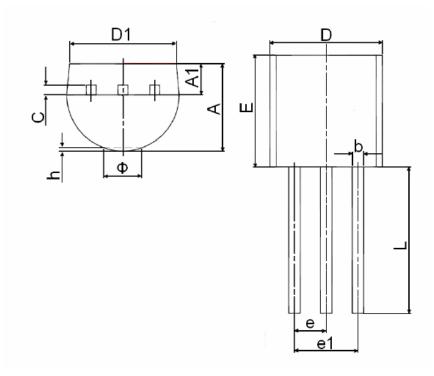


**Figure 11 Normalized Maximum Transient Thermal Impedance** 

Page 5 v1.0



## **TO-92 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
Α	3.300	3.700	0.130	0.146		
A1	1.100	1.400	0.043	0.055		
b	0.380	0.550	0.015	0.022		
С	0.360	0.510	0.014	0.020		
D	4.400	4.700	0.173	0.185		
D1	3.430		0.135			
E	4.300	4.700	0.169	0.185		
е	1.270	TYP	0.050 TYP			
e1	2.440	2.640	0.096	0.104		
L	14.100	14.500	0.555	0.571		
Ф		1.600		0.063		
h	0.000	0.380	0.000	0.015		

### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

Page 6 v1.0



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Page 7 v1.0